UNIVERSITY OF ESWATINI

FACULTY OF SCIENCE & ENGINEERING DEPARTMENT OF ELECTRICAL AND ELECTRONIC ENGINEERING

SUPPLIMENTARY / RESIT EXAMINATION JULY 2019

TITLE OF PAPER:

BASIC ELECTRONICS

COURSE CODE:

EEE222

TIME ALLOWED:

THREE HOURS

INSTRUCTIONS:

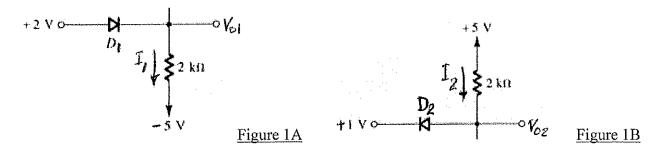
- 1. Answer all five (5) questions
- 2. Each question carries 20 marks.
- 3. Marks for different sections are shown in the right-hand margin.

This paper has 3 pages including this page.

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QUESTION 1

- A) For the circuits shown in Figure 1 A and Figure 1B using ideal diodes, find the values of the labelled voltages and currents. (15 marks)
- B) For the circuits shown in Figure 1 A using a diode with $V_D = 0.7$ V, find the value of current I_1 . (5 marks)



QUESTION 2

- a) Sketch the current voltage characteristics of a silicon diode and show all relevant details. (10 marks)
- b) Sketch the current voltage characteristics of a zener diode and show all relevant details. (10 marks)

QUESTION 3

For the circuit shown in Figure 3, derive the expression for the voltage V_0 and then find the voltage V_0 when $R_1=R_b=R_4=2~k\Omega$, $R_2=R_a=R_3=4~k\Omega$, and $R_c=5~k\Omega$ in terms of the inputs. (20 marks)

 $v_1 \circ \cdots \circ v_0$ $v_2 \circ \cdots \circ v_0$ $v_3 \circ \cdots \circ v_0$

QUESTION 4

If a MOSFET transistor has $g_m = 2 \times 10^{-3}$ and r_θ 100 k Ω ,

(a) Draw a complete small-signal equivalent circuit for the amplifier. (10 marks)

(b) Find R_{in} , v_{gs}/v_{isg} , v_o/v_{gs} , and v_o/v_{sig} . (10 marks)

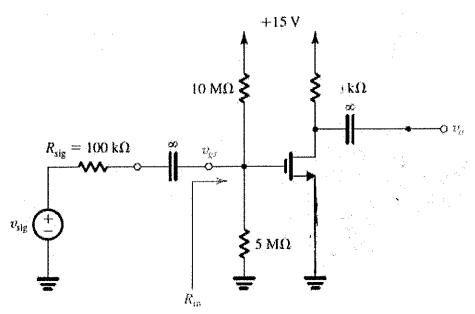
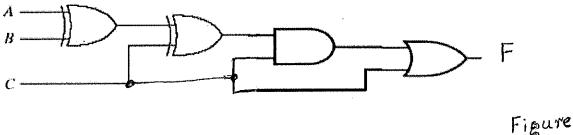


Figure 4

QUESTION 5

For the logic circuit shown in Figure \S , obtain the function F and then the truth table for the (20 marks) function F.



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Figure 5